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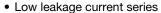
Vishay Semiconductors

# Power Silicon Rectifier Diodes, (Stud Version), 35 A, 40 A, 60 A



DO-5 (DO-203AB)

## **FEATURES**





Good surge current capability up to 1000 A

RoHS

 Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912">www.vishay.com/doc?99912</a>

| A, 40 A, 60 A |
|---------------|
| -5 (DO-203AB) |
| Single        |
|               |

| MAJOR RATINGS AND CHARACTERISTICS |                 |                          |                            |                          |                          |                   |
|-----------------------------------|-----------------|--------------------------|----------------------------|--------------------------|--------------------------|-------------------|
| PARAMETER                         | TEST CONDITIONS | 1N1183                   | 1N3765                     | 1N1183A                  | 1N2128A                  | UNITS             |
| 1                                 |                 | 35 <sup>(1)</sup>        | 35 <sup>(1)</sup>          | 40 <sup>(1)</sup>        | 60 <sup>(1)</sup>        | Α                 |
| I <sub>F(AV)</sub>                | T <sub>C</sub>  | 140 <sup>(1)</sup>       | 140 <sup>(1)</sup>         | 150 <sup>(1)</sup>       | 140 <sup>(1)</sup>       | °C                |
| 1                                 | 50 Hz           | 480                      | 380                        | 765                      | 860                      | ^                 |
| I <sub>FSM</sub>                  | 60 Hz           | 500 <sup>(1)</sup>       | 400 <sup>(1)</sup>         | 800 <sup>(1)</sup>       | 900 (1)                  | Α                 |
| I <sup>2</sup> t                  | 50 Hz           | 1140                     | 730                        | 2900                     | 3700                     | A <sup>2</sup> s  |
| 1-1                               | 60 Hz           | 1040                     | 670                        | 2650                     | 3400                     | A-S               |
| I <sup>2</sup> √t                 |                 | 16 100                   | 10 300                     | 41 000                   | 52 500                   | A <sup>2</sup> √s |
| V <sub>RRM</sub>                  | Range           | 50 to 600 <sup>(1)</sup> | 700 to 1000 <sup>(1)</sup> | 50 to 600 <sup>(1)</sup> | 50 to 600 <sup>(1)</sup> | V                 |
| TJ                                |                 | -65 to +200              | -65 to +200                | -65 to +200              | -65 to +200              | °C                |

#### Note

#### **ELECTRICAL SPECIFICATIONS**

| VOLTAGE RATINGS |            |            |  |   |  |  |
|-----------------|------------|------------|--|---|--|--|
| TYPE NUMBER     | 3          |            | V <sub>RRM</sub> , MAXIMUM REPETITIVE<br>PEAK REVERSE VOLTAGE<br>(T <sub>J</sub> = -65 °C to +200 °C <sup>(2)</sup> )<br>V | $V_{RM}$ , MAXIMUM DIRECT<br>REVERSE VOLTAGE<br>(T <sub>J</sub> = -65 °C to +200 °C <sup>(2)</sup> )<br>V |  |  |
| VS-1N1183       | VS-1N1183A | VS-1N2128A | 50 <sup>(1)</sup>  | 50 <sup>(1)</sup>   |  |  |
| VS-1N1184       | VS-1N1184A | VS-1N2129A | 100 (1)  | 100 (1)   |  |  |
| VS-1N1185       | VS-1N1185A | VS-1N2130A | 150 <sup>(1)</sup>   | 150 <sup>(1)</sup>  |  |  |
| VS-1N1186       | VS-1N1186A | VS-1N2131A | 200 (1)  | 200 (1)   |  |  |
| VS-1N1187       | VS-1N1187A | VS-1N2133A | 300 (1)  | 300 <sup>(1)</sup>  |  |  |
| VS-1N1188       | VS-1N1188A | VS-1N2135A | 400 (1)  | 400 (1)   |  |  |
| VS-1N1189       | VS-1N1189A | VS-1N2137A | 500 <sup>(1)</sup>   | 500 <sup>(1)</sup>  |  |  |
| VS-1N1190       | VS-1N1190A | VS-1N2138A | 600 <sup>(1)</sup>   | 600 <sup>(1)</sup>  |  |  |
| VS-1N3765       | VS-1N2160  |            | 700 (1)  | 700 <sup>(1)</sup>  |  |  |
| VS-1N3766       |            |            | 800 (1)  | 800 (1)   |  |  |
| VS-1N3767       |            |            | 900 (1)  | 900 (1)   |  |  |
| VS-1N3768       |            |            | 1000 (1)   | 1000 (1)  |  |  |

#### Notes

<sup>(1)</sup> JEDEC® registered values

Basic type number indicates cathode to case. For anode to case, add "R" to part number, e.g., 1N1188R, 1N3766R, 1N1186RA, 1N2135RA
JEDEC® registered values

 $<sup>^{(2)}</sup>$  For 1N1183 Series and 1N3765 Series  $T_C$  = -65  $^{\circ}$ C to +190  $^{\circ}$ C



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| PARAMETER  |                         | SYMBOL             | TEST CONDITIONS  |  | 1N1183                                  | 1N3765             | 1N1183A                                 | 1N2128A            | UNITS            |
|--|-------------------------|--------------------|--|--|---|--------------------|---|--------------------|------------------|
| Maximum average forward current at case temperature                        |                         | I <sub>F(AV)</sub> | 1-phase operation,<br>180° sinusoidal conduction   |  | 35 <sup>(1)</sup><br>140 <sup>(1)</sup> | 35 <sup>(1)</sup>  | 40 <sup>(1)</sup><br>150 <sup>(1)</sup> | 60 <sup>(1)</sup>  | A<br>°C          |
| Maximum peak one cycle non-repetitive surge current                        |                         | I <sub>FSM</sub>   | Half cycle 50 Hz<br>sine wave or 6 ms<br>rectangular pulse   | Following any<br>rated load<br>condition and<br>with rated<br>V <sub>RRM</sub> applied     | 480                                     | 380                | 765                                     | 860                | A                |
|  |                         |                    | Half cycle 60 Hz<br>sine wave or 5 ms<br>rectangular pulse   |  | 500 <sup>(1)</sup>                      | 400 (1)            | 800 (1)                                 | 900 (1)            |                  |
|  |                         |                    | Half cycle 50 Hz<br>sine wave or 6 ms<br>rectangular pulse   | Following any rated load condition and with ½ V <sub>RRM</sub> applied following surge = 0 | 570                                     | 455                | 910                                     | 1000               |                  |
|  |                         |                    | Half cycle 60 Hz<br>sine wave or 5 ms<br>rectangular pulse   |  | 595                                     | 475                | 950                                     | 1050               |                  |
| Maximum I <sup>2</sup> t for fusing  |                         |                    | t = 10 ms With rated V <sub>RRM</sub>  | 1140   | 730                                     | 2900               | 3700                                    |                    |                  |
|  |                         | - l <sup>2</sup> t | t = 8.3 ms   | applied following<br>surge, initial<br>$T_J = T_J$ maximum                                 | 1040                                    | 670                | 2650                                    | 3400               | A <sup>2</sup> s |
| Maximum I <sup>2</sup> t for individual device fusing                      |                         |                    | t = 10 ms  | With $V_{RRM} = 0$<br>following surge,<br>initial<br>$T_J = T_J$ maximum                   | 1610                                    | 1030               | 4150                                    | 5250               |                  |
|  |                         |                    | t = 8.3 ms   |  | 1470                                    | 940                | 3750                                    | 4750               |                  |
| Maximum I <sup>2</sup> √t for individual device fusing                     |                         | <b>I</b> 2√t (2)   | t = 0.1 to 10 ms,<br>V <sub>RRM</sub> = 0 following surge  |  | 16 100                                  | 10 300             | 41 500                                  | 52 500             | A²√s             |
| Maximum peak forward voltage at maximum forward current (I <sub>FM</sub> ) |                         | V <sub>FM</sub>    | T <sub>J</sub> = 25 °C   |  | 1.7 <sup>(1)</sup>                      | 1.8 <sup>(1)</sup> | 1.3 <sup>(1)</sup>                      | 1.3 <sup>(1)</sup> | V                |
|  |                         |                    |  |  | 110                                     | 110                | 126                                     | 188                | Α                |
| _  | $V_{RRM} = 700$         |                    |  |  | -                                       | 5.0 <sup>(1)</sup> | -                                       | -                  |                  |
| Maximum average  | $V_{RRM} = 800$         |                    | Maximum rated I <sub>F0</sub>  | <sub>AV)</sub> and T <sub>C</sub>  | -                                       | 4.0 (1)            | -                                       | -                  |                  |
| reverse current  | $V_{RRM} = 900$         | I <sub>R(AV)</sub> | The state of the s |  | -                                       | 3.0 (1)            | -                                       | -                  | mA               |
|  | V <sub>RRM</sub> = 1000 |                    |  |  | -                                       | 2.0 (1)            | -                                       | -                  |                  |
|  |                         |                    | Maximum rated I <sub>F(x</sub>   | 10 <sup>(1)</sup>  | -                                       | 2.5 <sup>(1)</sup> | 10 <sup>(1)</sup>                       |                    |                  |

### Notes

(1) JEDEC® registered values

(2)  $I^2t$  for time  $t_x = I^2\sqrt{t} \times \sqrt{t_x}$ 

| THERMAL AND MECHANICAL SPECIFICATIONS                 |                              |  |                                  |          |         |            |       |
|---|------------------------------|--|----------------------------------|----------|---------|------------|-------|
| PARAMETER   | SYMBOL                       | TEST CONDITIONS                                | 1N1183                           | 1N3765   | 1N1183A | 1N2128A    | UNITS |
| Maximum operating case temperature range              | T <sub>C</sub>               | -65 to +190 <sup>(1)</sup> -65                 |                                  | -65 to   | +200    | °C         |       |
| Maximum storage temperature range                     | T <sub>Stg</sub>             |  | -65 to +175 <sup>(1)</sup> -65 t |          | -65 to  | +200       |       |
| Maximum internal thermal resistance, junction to case | R <sub>thJC</sub>            | DC operation                                   | 1.0                              | 1.00 (1) |         | 0.65 (1)   | °C/W  |
| Thermal resistance, case to sink                      | R <sub>thCS</sub>            | Mounting surface, smooth, flat and greased     | 0.25                             |          |         | C/VV       |       |
|   |                              | Not lubricated thread, tighting on nut (2)     |                                  | 3.4      | 4 (30)  |            |       |
| Maximum allowable                                     |                              | Lubricated thread, tighting on nut (2)         |                                  | 2.       | 3 (20)  |            | N·m   |
| mounting torque<br>(+ 0 %, - 10 %)                    |                              | Not lubricated thread, tighting on hexagon (3) | 4.2 (37)                         |          |         | (lbf · in) |       |
| ( , . , , . ,   |                              | Lubricated thread, tighting on hexagon (3)     |                                  | 3.5      | 2 (28)  |            |       |
| Aiii  |                              |  |                                  |          | 17      |            | g     |
| Approximate weight                                    |                              |  |                                  |          | 0.6     |            | oz.   |
| Case style  | style JEDEC® DO-5 (DO-203AB) |  | AB)                              | •        |         |            |       |

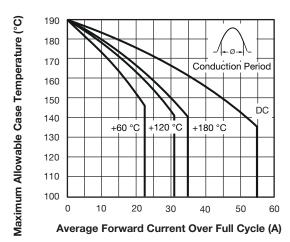
#### Notes

(1) JEDEC registered values®

(2) Recommended for pass-through holes

(3) Recommended for holed threaded heatsinks

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Fig. 1 - Maximum Allowable Case Temperature vs. Average Forward Current, 1N1183 and 1N3765 Series

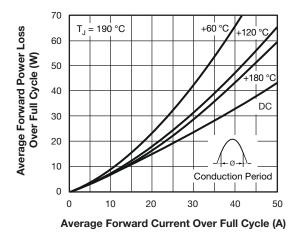


Fig. 2 - Typical Low Level Forward Power Loss vs. Average Forward Current (Sinusoidal Current Waveform), 1N1183 and 1N3765 Series

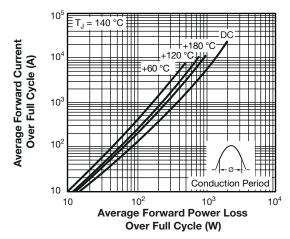


Fig. 3 - Typical High Level Forward Power Loss vs. Average Forward Current (Sinusoidal Current Waveform), 1N1183 and 1N3765 Series

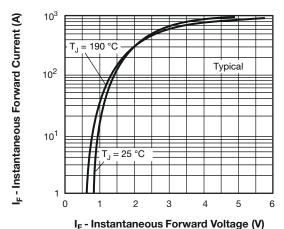


Fig. 4 - Typical Forward Voltage vs. Forward Current, 1N1183 and 1N3765 Series

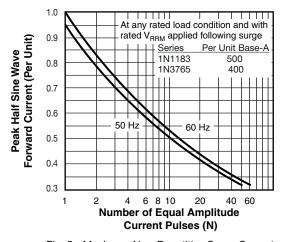
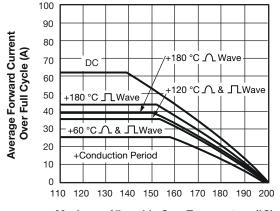


Fig. 5 - Maximum Non-Repetitive Surge Current vs. Number of Current Pulses, 1N1183 and 1N3765 Series



Maximum Allowable CaseTemperature (°C)

Fig. 6 - Average Forward Current vs. Maximum Allowable Case Temperature, 1N1183A Series



1.0

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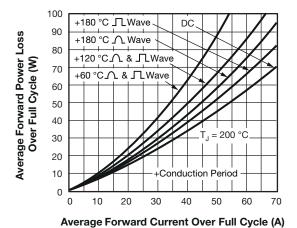


Fig. 7 - Maximum Low Level Forward Power Loss vs. Average Forward Current, 1N1183A Series

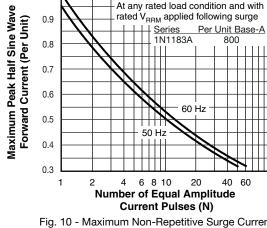
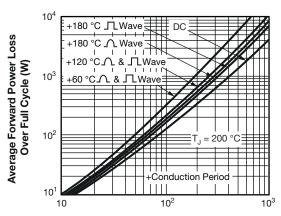


Fig. 10 - Maximum Non-Repetitive Surge Current vs. Number of Current Pulses, 1N1183A Series



Average Forward Current Over Full Cycle (A)

Fig. 8 - Maximum High Level Forward Power Loss vs. Average Forward Current, 1N1183A Series

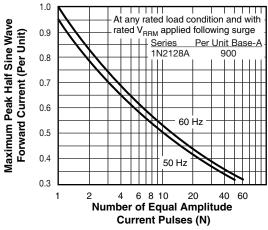


Fig. 11 - Maximum Non-Repetitive Surge Current vs. Number of Current Pulses, 1N2128A Series

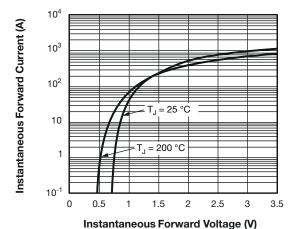


Fig. 9 - Maximum Forward Voltage vs. Forward Current, 1N1183A Series

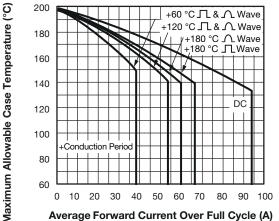


Fig. 12 - Maximum Allowable Case Temperature vs.

Average Forward Current, 1N2128A Series

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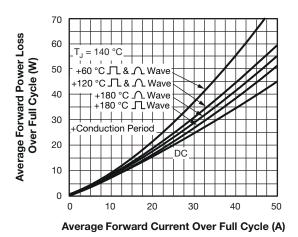
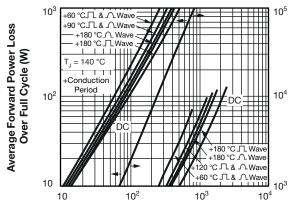


Fig. 13 - Maximum Low Level Forward Power Loss vs. Average Forward Current, 1N2128A Series



Average Forward Current Over Full Cycle (A)

Fig. 14 - Maximum High Level Forward Power Loss vs. Average Forward Current, 1N2128A Series

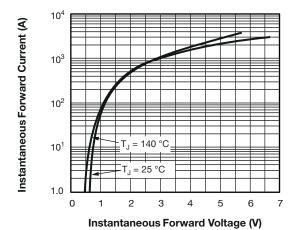


Fig. 15 - Maximum Forward Voltage vs. Forward Current, 1N2128A Series

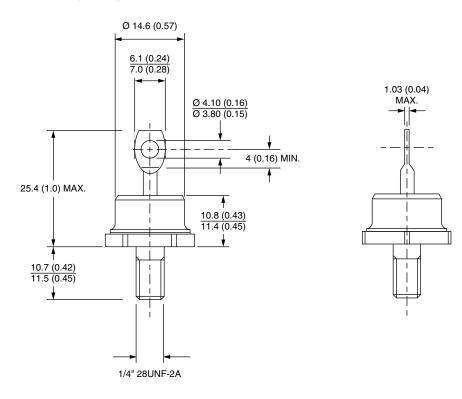
| LINKS TO RELATED DOCUMENTS |                          |  |  |  |
|----------------------------|--------------------------|--|--|--|
| Dimensions                 | www.vishay.com/doc?95360 |  |  |  |

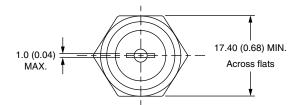


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# DO-203AB (DO-5) for 1N1183, 1N3765, 1N1183A, 1N2128A, 1N3208 Series

## **DIMENSIONS** in millimeters (inches)







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